**Product data sheet** 

# 1. General description

NPN low  $V_{CEsat}$  Breakthrough in Smal Signal (BISS) transitor in a medium power SOT89 (SC-62) flat lead Surface-Mounted Device (SMD) plastic package.

PNP complement: PBSS5360X

### 2. Features and benefits

- Low collector-emitter saturation voltage V<sub>CEsat</sub>
- High collector current capability I<sub>C</sub> and I<sub>CM</sub>
- · High energy efficiency due to less heat generation
- AEC-Q101 qualified

### 3. Applications

- · DC-to-DC conversion
- Supply line switching
- Battery charger
- LCD backlighting
- Driver in low supply voltage applications (e.g. lamps and LEDs)
- · Inductive load driver (e.g. relays, buzzers and motors)

#### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-	60	V
I <sub>C</sub>	collector current			-	-	3	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-	6	Α
R <sub>CEsat</sub>	collector-emitter saturation resistance	I <sub>C</sub> = 2 A; I <sub>B</sub> = 200 mA; T <sub>amb</sub> = 25 °C	[1]	-	-	140	mΩ

[1] Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ 



60 V, 3 A NPN low VCEsat BISS transistor

# 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	Е	emitter		С
2	С	collector		В
3	В	base	3 2 1	E E
			SOT89	sym123

# 6. Ordering information

### **Table 3. Ordering information**

Type number	Package	ckage				
	Name	Description	Version			
PBSS4360X	SOT89	plastic, surface-mounted package; 3 leads; 1.5 mm pitch; 4.5 mm x 2.5 mm x 1.5 mm body	SOT89			

# 7. Marking

#### Table 4. Marking codes

Type number	Marking code
PBSS4360X	S40

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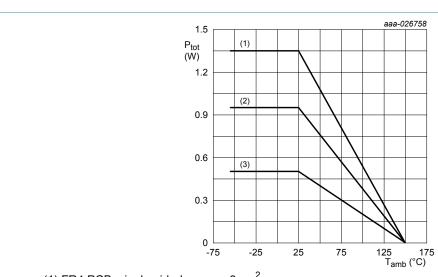
## 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter		-	80	V
$V_{CEO}$	collector-emitter voltage	open base		-	60	V
$V_{EBO}$	emitter-base voltage	open collector		-	7	V
I <sub>C</sub>	collector current			-	3	Α
I <sub>CM</sub>	peak collector current	single pulse; $t_p \le 1 \text{ ms}$		-	6	Α
I <sub>B</sub>	base current			-	500	mA
I <sub>BM</sub>	peak base current	single pulse; t <sub>p</sub> ≤ 1 ms		-	1	Α
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	500	mW
			[2]	-	950	mW
			[3]	-	1.35	W
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

- Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated; mounting pad for collector 1 cm<sup>2</sup>. Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated; mounting pad for collector 6 cm<sup>2</sup>.



- (1) FR4 PCB, single-sided copper, 6 cm<sup>2</sup>
- (2) FR4 PCB, single-sided copper, 1 cm<sup>2</sup>
- (3) FR4 PCB, single-sided copper, standard footprint

Fig. 1. Power derating curves

60 V, 3 A NPN low VCEsat BISS transistor

### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
uig a)	thermal resistance from junction to ambient		[1]	-	-	250	K/W
			[2]	-	-	132	K/W
			<u>[3]</u>	-	-	93	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm<sup>2</sup>.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 6 cm<sup>2</sup>.

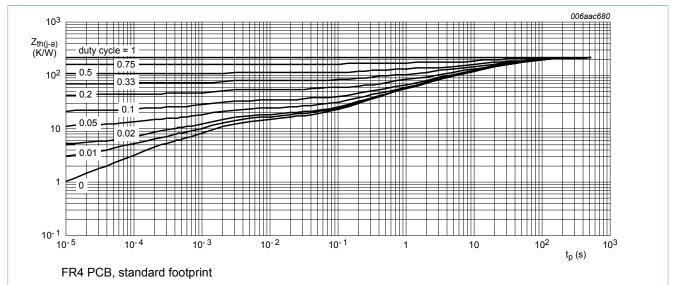


Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

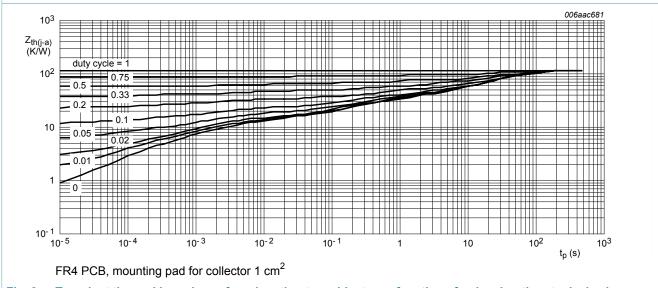
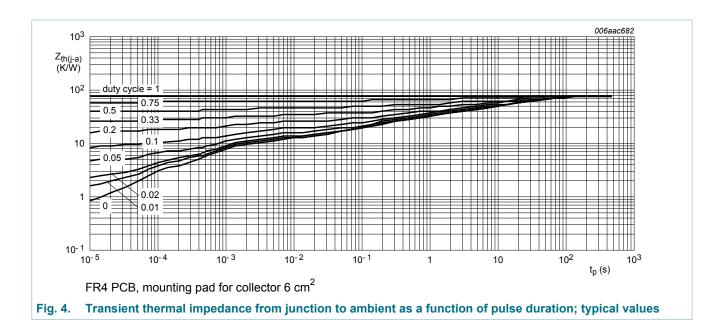


Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

#### 60 V, 3 A NPN low VCEsat BISS transistor



60 V, 3 A NPN low VCEsat BISS transistor

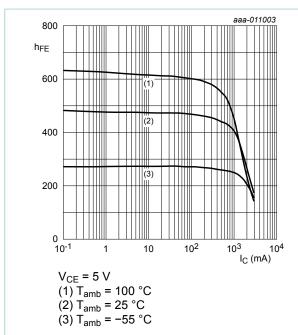
### 10. Characteristics

**Table 7. Characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	V <sub>CB</sub> = 48 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	100	nA
	current	V <sub>CB</sub> = 48 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C		-	-	50	μΑ
I <sub>CES</sub>	collector-emitter cut-off current	$V_{CE} = 48 \text{ V}; V_{BE} = 0 \text{ V}; T_{amb} = 25 ^{\circ}\text{C}$		-	-	100	nA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-	-	100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 50 mA; T <sub>amb</sub> = 25 °C		200	-	-	
		$V_{CE}$ = 5 V; $I_{C}$ = 500 mA; $T_{amb}$ = 25 °C	[1]	200	-	-	
		V <sub>CE</sub> = 5 V; I <sub>C</sub> = 1 A; T <sub>amb</sub> = 25 °C	[1]	200	-	-	
		V <sub>CE</sub> = 5 V; I <sub>C</sub> = 2 A; T <sub>amb</sub> = 25 °C	[1]	120	-	-	
		$V_{CE}$ = 5 V; $I_{C}$ = 3 A; $T_{amb}$ = 25 °C	[1]	75	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C$ = 500 mA; $I_B$ = 50 mA; $T_{amb}$ = 25 °C	[1]	-	-	75	mV
		$I_C$ = 1 A; $I_B$ = 100 mA; $T_{amb}$ = 25 °C	[1]	-	-	150	mV
		$I_C$ = 2 A; $I_B$ = 200 mA; $T_{amb}$ = 25 °C	[1]	-	-	275	mV
		$I_C$ = 3 A; $I_B$ = 300 mA; $T_{amb}$ = 25 °C	[1]	-	-	400	mV
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_C = 2 \text{ A}; I_B = 200 \text{ mA}; T_{amb} = 25 \text{ °C}$	[1]	-	-	140	mΩ
$V_{BEsat}$	base-emitter saturation voltage	$I_C = 1 \text{ A}; I_B = 100 \text{ mA}; T_{amb} = 25 \text{ °C}$	[1]	-	-	1.2	V
$V_{BEon}$	base-emitter turn-on voltage	$V_{CE}$ = 5 V; $I_{C}$ = 1 A; $T_{amb}$ = 25 °C	[1]	-	-	1.1	V
f <sub>T</sub>	transition frequency	$V_{CE}$ = 10 V; $I_{C}$ = 50 mA; f = 100 MHz; $T_{amb}$ = 25 °C		75	145	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB}$ = 10 V; $I_{E}$ = 0 A; $i_{e}$ = 0 A; $f$ = 1 MHz; $T_{amb}$ = 25 °C		-	11	14	pF

<sup>[1]</sup> Pulse test:  $t_p \le 300 \ \mu s; \ \delta \le 0.02$ 

#### 60 V, 3 A NPN low VCEsat BISS transistor



DC current gain as a function of collector Fig. 5. current; typical values

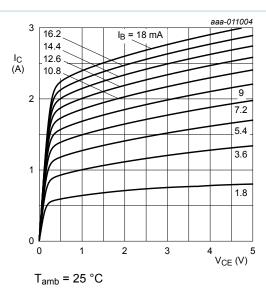
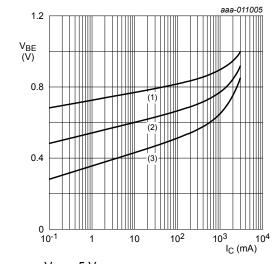


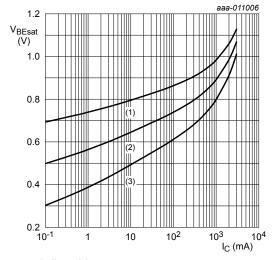
Fig. 6. Collector current as a function of collectoremitter voltage; typical values



 $V_{CE} = 5 V$ (1)  $T_{amb} = -55 °C$ 

(2)  $T_{amb} = 25 \,^{\circ}C$ (3)  $T_{amb} = 100 \,^{\circ}C$ 

Fig. 7. Base-emitter voltage as a function of collector current; typical values



 $I_C/I_B = 20$ (1)  $T_{amb} = -55$  °C

(2) T<sub>amb</sub> = 25 °C (3) T<sub>amb</sub> = 100 °C

Fig. 8. Base-emitter saturation voltage as a function of collector current; typical values

7 / 13

### 60 V, 3 A NPN low VCEsat BISS transistor

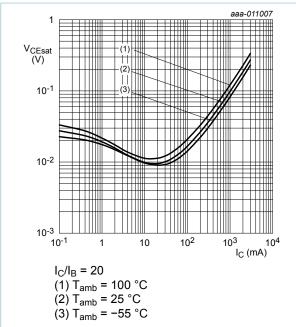


Fig. 9. Collector-emitter saturation voltage as a function of collector current; typical values

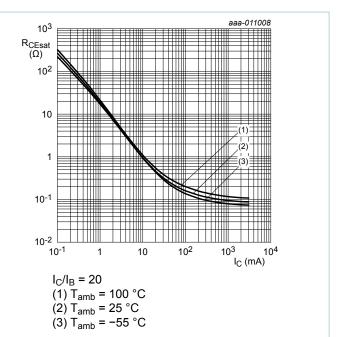


Fig. 10. Collector-emitter saturation resistance as a function of collector current; typical values

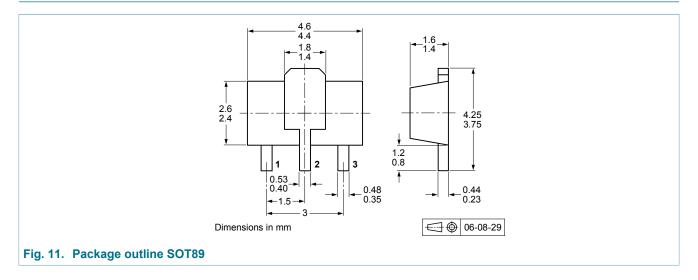
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## 11. Test information

### **Quality information**

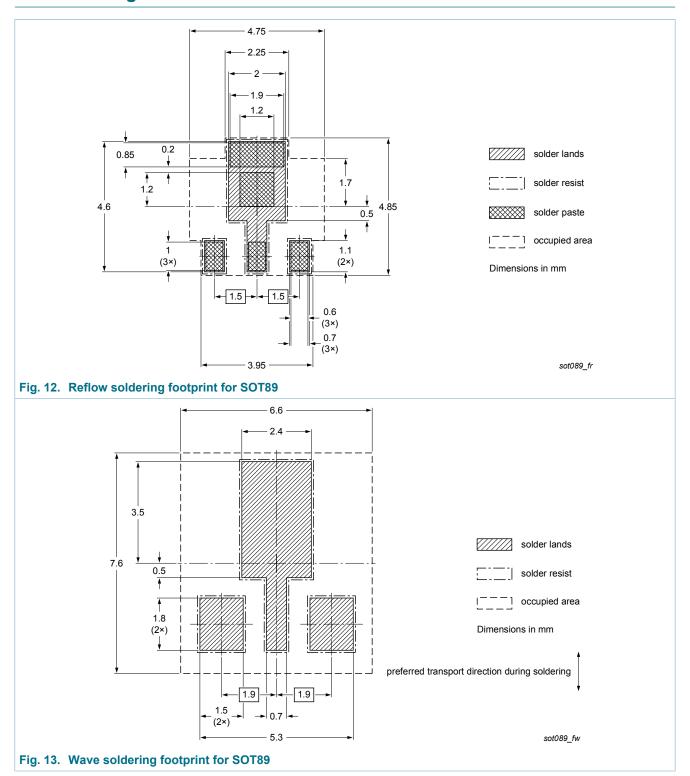
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

# 12. Package outline



60 V, 3 A NPN low VCEsat BISS transistor

## 13. Soldering



60 V, 3 A NPN low VCEsat BISS transistor

# 14. Revision history

### **Table 8. Revision history**

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PBSS4360X v.1	20170609	Product data sheet	-	-

### 60 V, 3 A NPN low VCEsat BISS transistor

# 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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### 60 V, 3 A NPN low VCEsat BISS transistor

### 16. Contents

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	2
8.	Limiting values	3
9.	Thermal characteristics	4
10.	Characteristics	6
11.	Test information	9
12.	Package outline	9
13.	Soldering	10
14.	Revision history	.11
	Legal information	

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13 / 13

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